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(54)SUPERCONDUCTIVITY IN SQUARE-PLANAR COMPOUND SYSTEMS

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(*) Notice: Subject to any disclaimer, the term of this

patent is extended or adjusted under 35

U.S.C. 154(b) by 785 days.

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Related U.S. Application Data

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U.S. Cl. 505/125; 505/126; 505/490; 505/500; 505/780

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> 505/500 See application file for complete search history.

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ABSTRACT (57)

Described is a superconducting composition comprising an oxide complex of the formula $[L_{1-x}M_x]_aA_bO_v$, wherein L is lanthanum, lutetium, yttrium, or scandium; A is copper, bismuth, titanium, tungsten, zirconium, tantalum, niobium, or vanadium; M is barium, strontium, calcium, magnesium or mercury; and "a" is 1 to 2; "b" is 1; and "x" is a number in the range of 0.01 to 1.0; and "y" is about 2 to about 4. The oxide complexes of the invention are prepared by a solidstate reaction procedure which produces an oxide complex having an enhanced superconducting transition temperature compared to an oxide complex of like empirical composition prepared by a coprecipitation—high temperature decomposition procedure. With an oxide complex prepared by the solid-state reaction of the invention a transition temperature as high as 100°K has been observed even under atmospheric pressure.

15 Claims, 5 Drawing Sheets

